

# 45 V, 100 mA PNP general-purpose transistor Rev. 01 — 19 March 2007

Product data sheet

#### 1. **Product profile**

#### 1.1 General description

PNP general-purpose transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: 2PD601ART.

#### 1.2 Features

- General-purpose transistor
- Small SMD plastic package

#### 1.3 Applications

General-purpose switching and amplification

#### 1.4 Quick reference data

| Table 1.        | Quick reference data      |  |     |     |      |      |
|-----------------|---------------------------|--|-----|-----|------|------|
| Symbol          | Parameter                 | Conditions   | Min | Тур | Max  | Unit |
| $V_{CEO}$       | collector-emitter voltage | open base  | -   | -   | -45  | V    |
| l <sub>C</sub>  | collector current         |  | -   | -   | -100 | mA   |
| h <sub>FE</sub> | DC current gain           | V <sub>CE</sub> = -10 V;<br>I <sub>C</sub> = -2 mA | 210 | -   | 340  |      |

#### **Pinning information** 2.

| Pin | Description | Simplified outline | Symbol |
|-----|-------------|--------------------|--------|
| 1   | base        |                    |        |
| 2   | emitter     |                    | 3      |
| 3   | collector   |                    |        |
|     |             |                    | sym013 |



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### 3. Ordering information

| Table 3. Order | ring informa | ation                                    |         |
|----------------|--------------|--|---------|
| Type number    | Package      |  |         |
|                | Name         | Description                              | Version |
| 2PB709ART      | -            | plastic surface-mounted package; 3 leads | SOT23   |

### 4. Marking

| Table 4. Mar | ing codes                   |
|--------------|-----------------------------|
| Type number  | Marking code <sup>[1]</sup> |
| 2PB709ART    | C5*                         |
|              |                             |

- [1] \* = -: made in Hong Kong
  - \* = p: made in Hong Kong
  - \* = t: made in Malaysia
  - \* = W: made in China

### 5. Limiting values

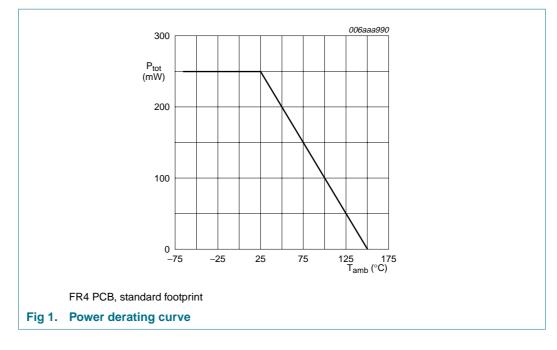
#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Tjjunction temperature-150°CT_ambambient temperature-65+150°C   | Symbol           | Parameter                 | Conditions                   | Min          | Max  | Unit |
|---|------------------|---------------------------|------------------------------|--------------|------|------|
| $ \begin{array}{c c c c c c c c c c c c c c c c c c c $   | V <sub>CBO</sub> | collector-base voltage    | open emitter                 | -            | -45  | V    |
| I_LBCcollector current100mAI_Ccollector currentsingle pulse;<br>$t_p \le 1 \text{ ms}$ 200mAI_BMpeak base currentsingle pulse;<br>$t_p \le 1 \text{ ms}$ 100mAP_tottotal power dissipationT_amb \le 25 °C11-250mWT_jjunction temperature-150°CT_ambambient temperature-65+150°C   | V <sub>CEO</sub> | collector-emitter voltage | open base                    | -            | -45  | V    |
| $      I_{CM} \qquad \mbox{peak collector current} \qquad \mbox{single pulse;} \\ t_p \le 1 \mbox{ ms} \qquad \mbox{200} \qquad \mbox{mA} \\      I_{BM} \qquad \mbox{peak base current} \qquad \mbox{single pulse;} \\ t_p \le 1 \mbox{ ms} \qquad \mbox{100} \qquad \mbox{mA} \\      P_{tot} \qquad \mbox{total power dissipation} \qquad \mbox{T}_{amb} \le 25 \ ^{\circ}\text{C} \qquad \mbox{[1]} \ \mbox{200} \qquad \mbox{mA} \\      T_j \qquad \mbox{junction temperature} \qquad \mbox{100} \qquad \mbox{mA} \\      T_{amb} \qquad \mbox{ambient temperature} \qquad \mbox{100} \qquad \mbox{mA} \\      -100 \qquad \mbox{mA} \\      T_{amb} \qquad \mbox{mbox{min}} \ \mbox{100} \qquad \mbox{mA} \\      T_{amb} \qquad \mbox{mbox{min}} \ \mbox{min} \ \mbox{mbox{min}} \ \mbox{min} \ \mbox{mbox{min}} \ \mbox{mbox{min}} \ \mbox{mbox{min}} \ \mbox{mbox{min}} \ \mbox{mbox{min}} \ \mbox{min} \ \mbox$ | V <sub>EBO</sub> | emitter-base voltage      | open collector               | -            | -6   | V    |
| total power dissipation $T_{amb} \le 25 \text{ °C}$ [1]100mAPtottotal power dissipation $T_{amb} \le 25 \text{ °C}$ [1]-250mWTjjunction temperature-150°CT_{amb}ambient temperature-65+150°C  | I <sub>C</sub>   | collector current         |                              | -            | -100 | mA   |
| $\begin{array}{c c c c c c c c c c c c c c c c c c c $  | I <sub>CM</sub>  | peak collector current    | • •                          | -            | -200 | mA   |
| Tjjunction temperature-150°CT_ambambient temperature-65+150°C   | I <sub>BM</sub>  | peak base current         | • •                          | -            | -100 | mA   |
| $T_{amb}$ ambient temperature $-65 +150$ °C   | P <sub>tot</sub> | total power dissipation   | $T_{amb} \le 25 \ ^{\circ}C$ | <u>[1]</u> - | 250  | mW   |
|   | Tj               | junction temperature      |                              | -            | 150  | °C   |
| $T_{stg}$ storage temperature $-65$ +150 °C   | T <sub>amb</sub> | ambient temperature       |                              | -65          | +150 | °C   |
|   | T <sub>stg</sub> | storage temperature       |                              | -65          | +150 | °C   |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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## 6. Thermal characteristics

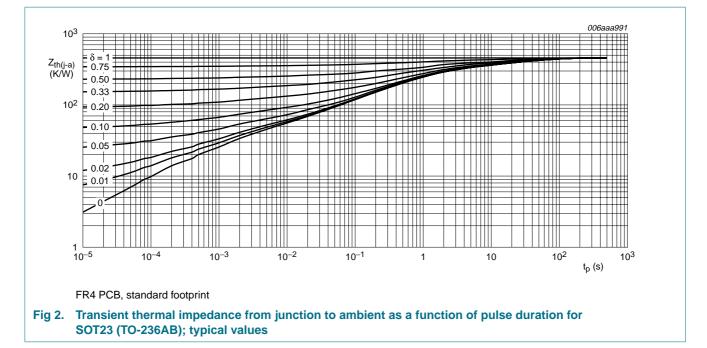
| Table 6.              | Thermal characteristics                          |             |              |     |     |      |
|-----------------------|--|-------------|--------------|-----|-----|------|
| Symbol                | Parameter  | Conditions  | Min          | Тур | Max | Unit |
| R <sub>th(j-a)</sub>  | thermal resistance from junction to ambient      | in free air | <u>[1]</u> - | -   | 500 | K/W  |
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |             | -            | -   | 140 | K/W  |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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### 7. Characteristics

#### Table 7.Characteristics

 $T_{amb} = 25 \circ C$  unless otherwise specified.

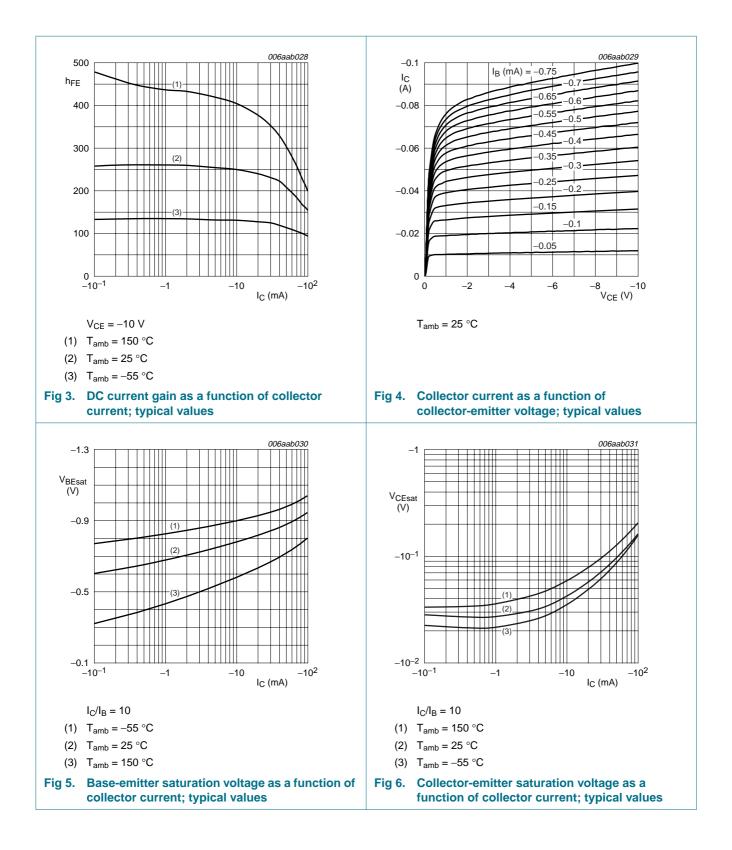
| Symbol             | Parameter                            | Conditions   |            | Min | Тур | Max  | Unit |
|--------------------|--------------------------------------|--|------------|-----|-----|------|------|
| I <sub>CBO</sub>   | collector-base cut-off               | $V_{CB} = -45 \text{ V}; I_E = 0 \text{ A}$                            |            | -   | -   | -10  | nA   |
|                    | current                              | $V_{CB} = -45 \text{ V}; I_E = 0 \text{ A};$<br>$T_j = 150 \text{ °C}$ |            | -   | -   | -5   | μA   |
| I <sub>EBO</sub>   | emitter-base cut-off current         | $V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$                   |            | -   | -   | -10  | nA   |
| h <sub>FE</sub>    | DC current gain                      | $V_{CE} = -10 \text{ V};$<br>$I_C = -2 \text{ mA}$                     |            | 210 | -   | 340  |      |
| V <sub>CEsat</sub> | collector-emitter saturation voltage | $I_{\rm C} = -100 \text{ mA};$<br>$I_{\rm B} = -10 \text{ mA}$         | <u>[1]</u> | -   | -   | -500 | mV   |
| f <sub>T</sub>     | transition frequency                 | $V_{CE} = -10 V;$<br>$I_{C} = -1 mA;$<br>f = 100 MHz                   |            | 70  | -   | -    | MHz  |
| C <sub>c</sub>     | collector capacitance                | $V_{CB} = -10 V;$<br>$I_E = i_e = 0 A;$<br>f = 1 MHz                   |            | -   | -   | 5    | pF   |

[1] Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ .

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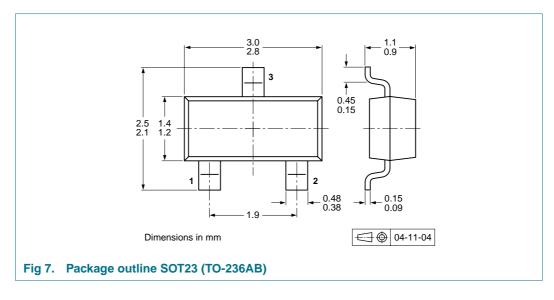
## **2PB709ART**

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### 8. Package outline

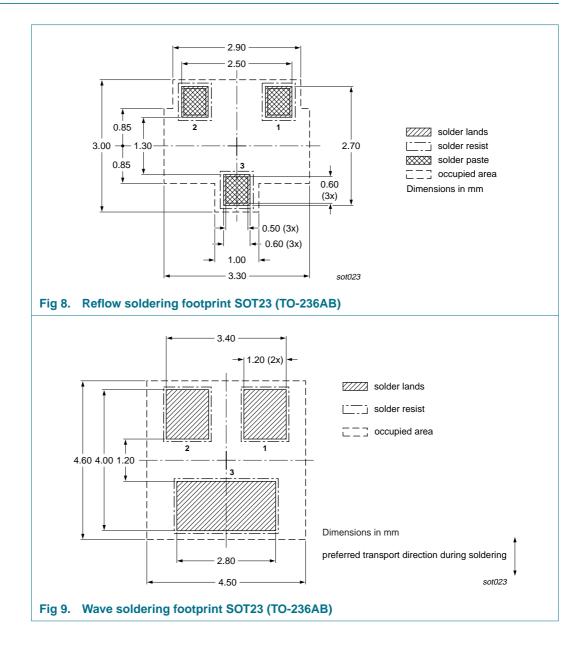


## 9. Packing information

Please refer to packing information on <u>www.nexperia.com</u>.

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### **10. Soldering**



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## **11. Revision history**

| Table 9. | <b>Revision histo</b> | ory          |                    |               |            |
|----------|-----------------------|--------------|--------------------|---------------|------------|
| Document | : ID                  | Release date | Data sheet status  | Change notice | Supersedes |
| 2PB709AR | T                     | 20070319     | Product data sheet | -             | -          |

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### 12. Legal information

#### **12.1 Data sheet status**

| Document status[1][2]          | Product status <sup>[3]</sup> | Definition  |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet   | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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